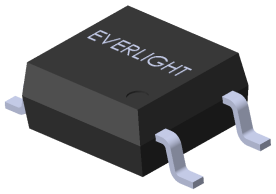
4 PIN SOP HIGH VOLTAGE DARLINGTON PHOTOTRANSISTOR PHOTOCOUPLER

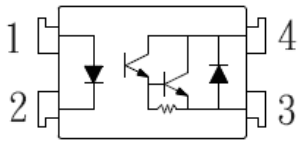
EL452-G Series

Features:

- Halogens free
- High collect-Emitter voltage (V_{CEO} = 350V)
- Current transfer ratio
  (CTR: Min. 1000% at I_F =1mA ,V_{CE} =2V)
- High isolation voltage between input
  and output (Viso=3750 V rms)
- Compact 4 Pin SOP with a 2.0 mm profile
- Pb free and RoHS compliant.
- UL approved (Pending)
- VDE approved (Pending)
- SEMKO approved (Pending)
- NEMKO approved (Pending)
- DEMKO approved (Pending)
- FIMKO approved (Pending)
- CSA approved (Pending)



Schematic



Pin Configuration
1. Anode
2. Cathode
3. Emitter
4. Collector

Description

The EL452-G contains an infrared emitting diode, optically coupled to a high voltage darlington phototransistor.
It is packaged in a 4-pin small outline SMD package.

Applications

- Telephone set, telephone exchangers
- Sequence controllers
- System appliances, measuring instruments
- Signal transmission between circuits of different potentials and impedance

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Absolute Maximum Ratings (T_a=25℃)

Parameter		Symbol	Rating	Unit
Input	Forward current	I_F	60	mA
	Peak forward current (t = 10μs)	I_{FM}	1	A
	Power dissipation	P_D	100	mW
Output	Power dissipation	P_C	150	mW
	Collector current	I_C	150	mA
	Collector-Emitter voltage	V_{CEO}	350	V
	Emitter-Collector voltage	V_{ECO}	0.1	V
Total power dissipation		P_{tot}	170	mW
Isolation voltage *1		V_{iso}	3750	V rms
Operating temperature		T_{opr}	-55~+110	℃
Storage temperature		T_{stg}	-55~+125	℃
Soldering temperature *2		T_{sol}	260	℃

Notes

*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1 & 2 are shorted together, and pins 3 & 4 are shorted together.

*2 For 10 seconds.

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Electrical Characteristics (T_a=25℃ unless specified otherwise)

Input

Parameter	Symbol	Min.	Typ.*	Max.	Unit	Condition
Forward voltage	V_F	-	1.2	1.4	V	I_F = 10mA
Reverse current	I_R	-	-	10	μA	V_R = 4V
Input capacitance	C_{in}	-	50	-	pF	V = 0, f = 1KHz

Output

Parameter	Symbol	Min.	Typ.*	Max.	Unit	Condition
Collector-Emitter dark current	I_{CEO}	-	-	100	nA	V_{CE} = 200V, I_F=0mA
Collector-Emitter breakdown voltage	BV_{CEO}	350	-	-	V	I_c=0.1mA
Emitter-Collector breakdown voltage	BV_{ECO}	0.1	-	-	V	I_E=0.01mA

Transfer Characteristics (T_a=25℃ unless specified otherwise)

Parameter	Symbol	Min.	Typ.*	Max.	Unit	Condition
Current Transfer ratio	CTR	1000	2000	-	%	I_F = 1mA ,V_{CE} = 2V
Collector-emitter saturation voltage	$V_{CE(sat)}$	-	1.2	1.5	V	I_F = 20mA ,I_c = 100mA
Isolation resistance	R_{IO}	5×10^{10}	10^{11}	-	Ω	V_{IO} = 500Vdc, 40~60%R.H
Cut-off frequency	fc	-	7	-	KHz	V_{CE}=2V, I_C=2mA,R_L=100Ω, -3db
Floating capacitance	C_{IO}	-	0.6	-	pF	V_{IO} = 0, f = 1MHz
Rise time	T_r	-	80	250	μs	V_{CE}=2V, I_C=20mA,R_L=100Ω
Fall time	T_f	-	10	100	μs	

* Typical values at T_a = 25℃

Typical Performance Curves

Figure 1. Forward Current vs. Forward Voltage

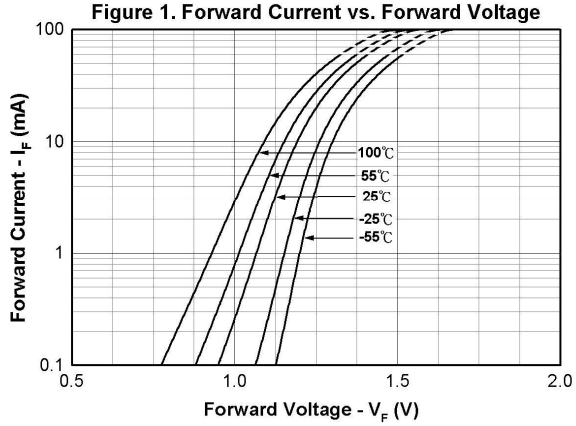


Figure 2. Collector Current vs. Collector Emitter Voltage

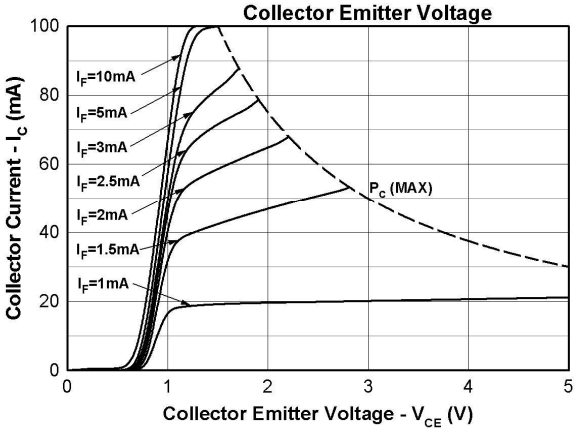


Figure 3. Collector Emitter Saturation Voltage vs. Ambient Temperature

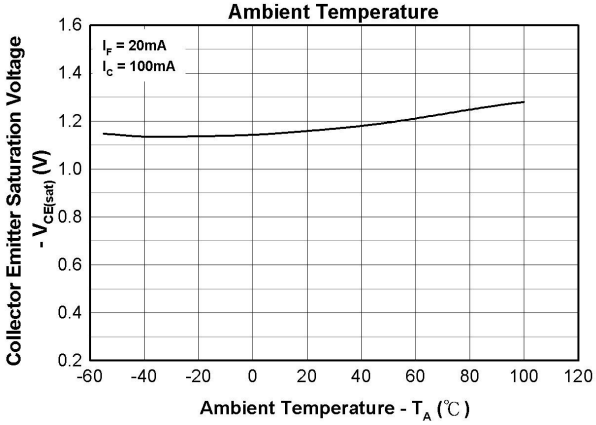


Figure 4. Collector-Emitted Saturation Voltage vs. Forward Current

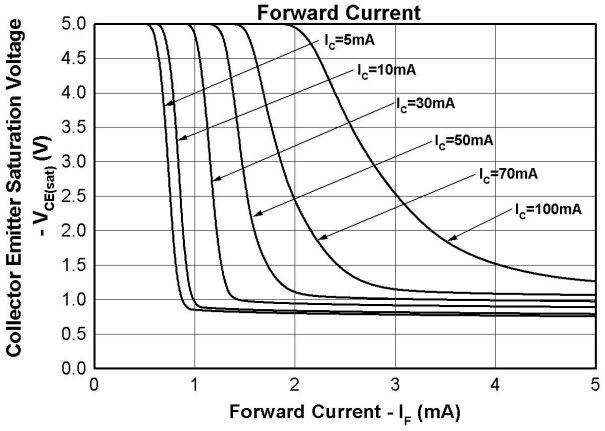


Figure 5. Current Transfer Ratio vs. Forward Current

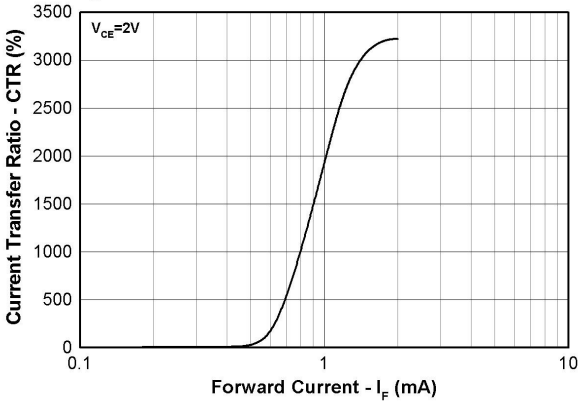


Figure 6. Normalized Current Transfer Ratio vs. Ambient Temperature

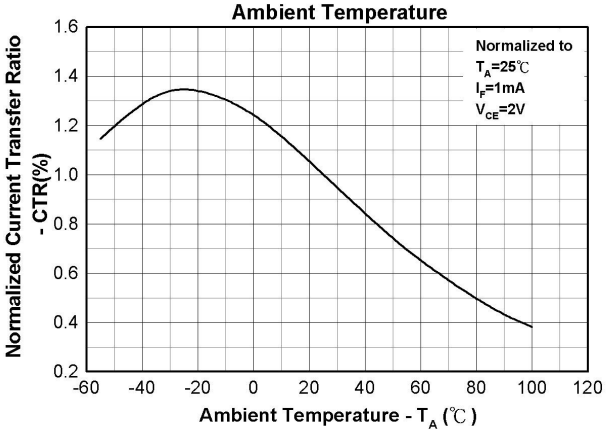


Figure 7. Collector Dark Current vs. Ambient Temperature

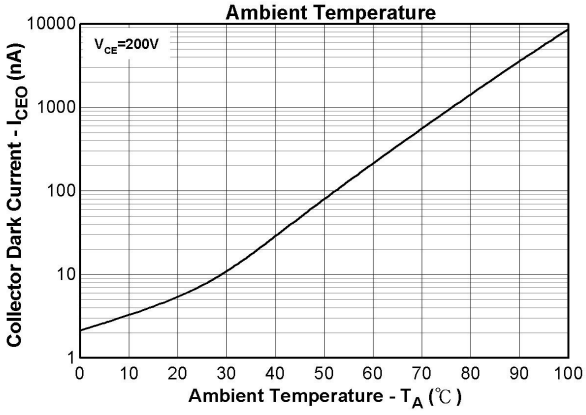


Figure 8. Response Time vs. Load Resistance

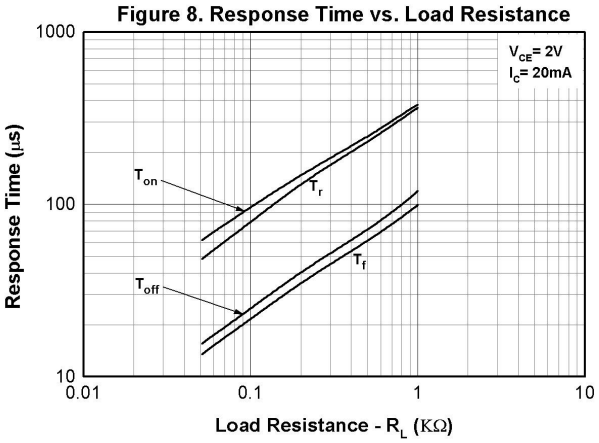
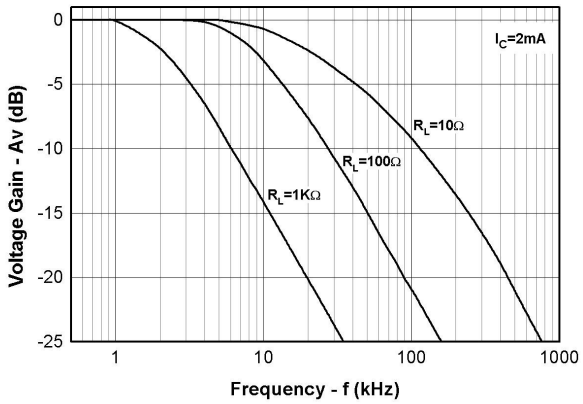


Figure 9. Frequency Response



Order Information

Part Number

EL452(Y)-VG

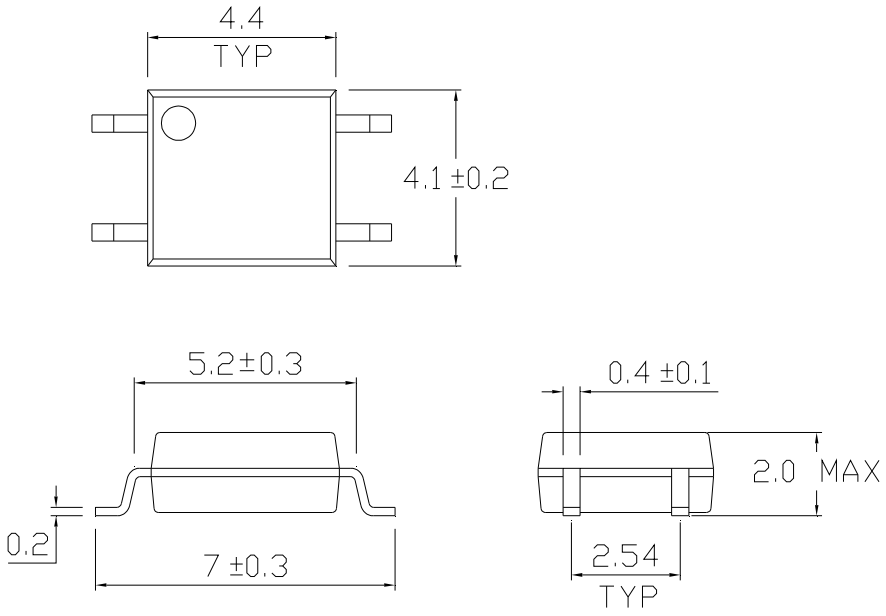
Note

Y = Tape and reel option (TA, TB, or none).
V = VDE safety (optional)
G = Halogens free

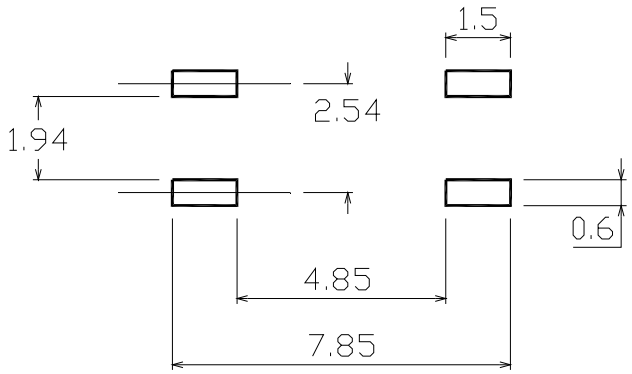
Option	Description	Packing quantity
None	Standard SMD option	100 units per tube
-V	Standard SMD option + VDE	100 units per tube
(TA)	TA Tape & reel option	3000 units per reel
(TB)	TB Tape & reel option	3000 units per reel
(TA)-V	TA Tape & reel option + VDE	3000 units per reel
(TB)-V	TB Tape & reel option + VDE	3000 units per reel

Package Drawings

(Dimensions in mm)



Recommended pad layout for surface mount leadform



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Device Marking

Notes

EL	denotes Everlight
452	denotes Part Number
Y	denotes 1 digit Year code
WW	denotes 2 digit Week code
V	denotes VDE approved (optional)

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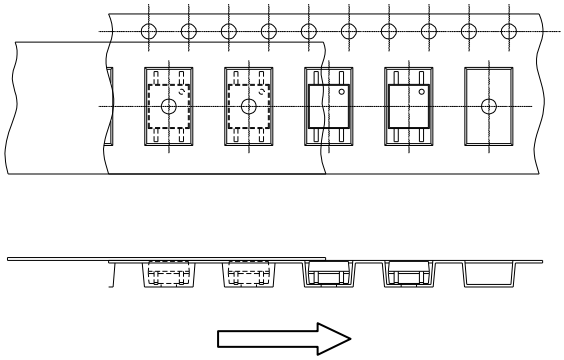
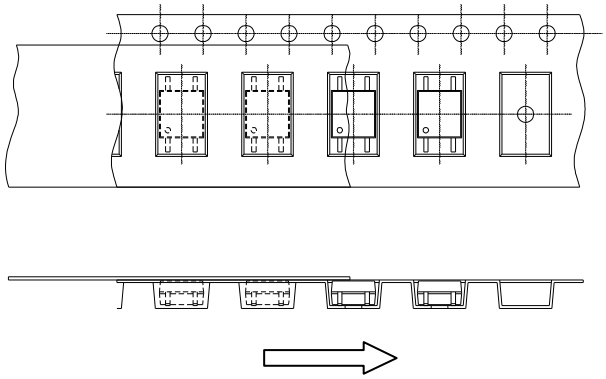
Tape & Reel Packing Specifications

Option TA



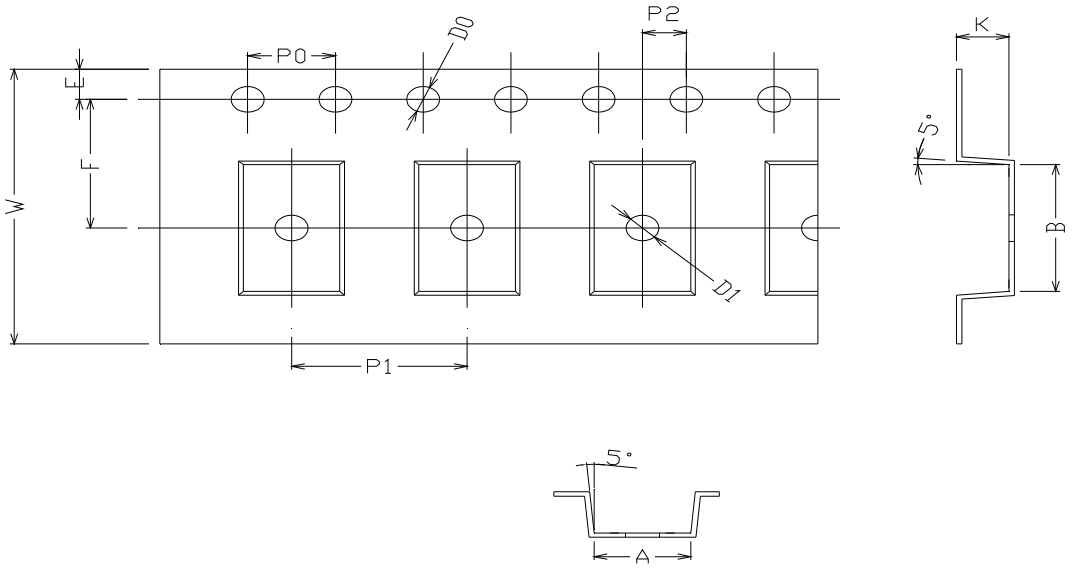
Direction of feed from reel

Option TB



Direction of feed from reel

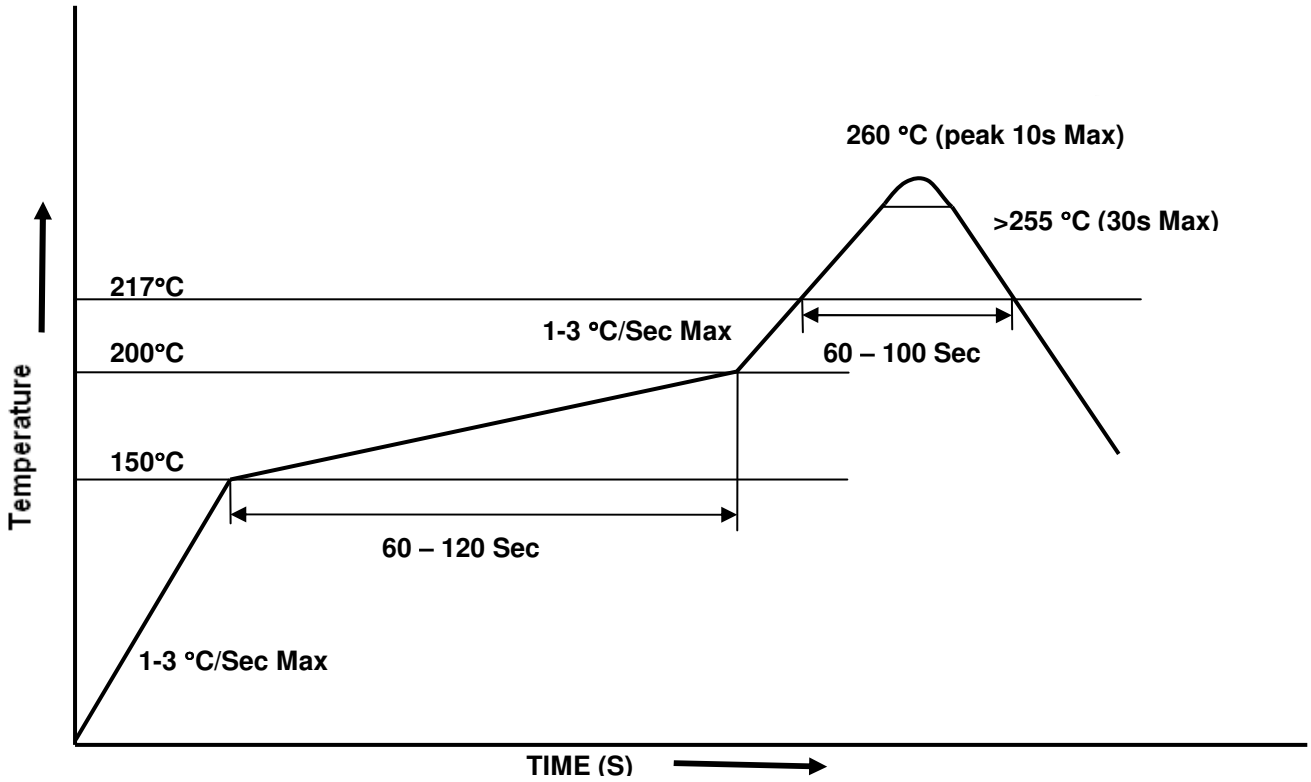
Tape dimensions



Dimension No.	A	B	Do	D1	E	F
Dimension (mm)	4.4 ± 0.1	7.4 ± 0.1	1.5 + 0.1/-0	1.5 ± 0.1	1.7 5± 0.1	7.5 ± 0.1

Dimension No.	Po	P1	P2	t	W	K
Dimension (mm)	4.0 ± 0.15	8.0 ± 0.1	2.0 ± 0.1	0.25 ± 0.03	16.0 ± 0.2	2.4 ± 0.1

Solder Reflow Temperature Profile



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